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Substitute for form 1449A/PTO				Complete if Known		
				Application Number	10/087,744	
11	NFORMATIO	N DI	SCLOSURE	Filing Date	March 5, 2002	
S	STATEMENT BY APPLICANT (use as many sheets as necessary)			First Named Inventor	Glen Hush	
				Art Unit	2818	
				Examiner Name	T. Le	
Sheet	2	of	4	Attorney Docket Number	M4065.0485/P485	

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Signature Cite 9 tc		1/2

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¹ Applicant's unique citation designation number (optional). ² See attached Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3), ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the application number of the patent document by the appropriate symbols as indicated on the document under WIPO Standard ST. 18 if possible. ⁴ Applicant is to place a check mark here if English tanguage Translation is attached.

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